

# SOT-23 Dual Monolithic Common Anode Zener Transient Voltage Suppressor For ESD Protection

This dual monolithic silicon zener diode is designed for applications requiring transient overvoltage protection capability. It is intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Its dual junction common anode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

**Specification Features:**

- SOT-23 Package Allows Either Two Separate Unidirectional Configurations or a Single Bidirectional Configuration
- Peak Power — 24 Watts @ 1.0 ms (Unidirectional), per Figure 5 Waveform
- Maximum Clamping Voltage @ Peak Pulse Current
- Low Leakage < 5.0  $\mu$ A
- ESD Rating of Class N (exceeding 16 kV) per the Human Body Model

**Mechanical Characteristics:**

- Void Free, Transfer-Molded, Thermosetting Plastic Case
- Corrosion Resistant Finish, Easily Solderable
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- Available in 8 mm Tape and Reel  
Use the Device Number to Order the 7 inch/3,000 Unit Reel  
Replace "T1" with "T3" in the Device Number to Order the 13 inch/10,000 Unit Reel

**WAFER FAB LOCATION:** Phoenix, Arizona

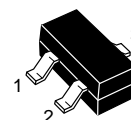
**ASSEMBLY/TEST LOCATION:** Seremban, Malaysia

## MMBZ5V6ALT1

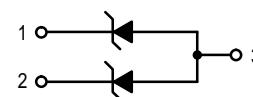
ADDITIONAL VOLTAGES AVAILABLE

Motorola Preferred Device

**SOT-23 DUAL  
ZENER OVERVOLTAGE  
TRANSIENT SUPPRESSOR  
5.6 VOLTS  
24 WATTS PEAK POWER**



**CASE 318-07  
STYLE 12  
LOW PROFILE SOT-23  
PLASTIC**



PIN 1. CATHODE  
2. CATHODE  
3. ANODE

**THERMAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Value	Unit
Peak Power Dissipation @ 1.0 ms (1) @ $T_A \leq 25^\circ\text{C}$	$P_{pk}$	24	Watts
Total Power Dissipation on FR-5 Board (2) @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Power Dissipation on Alumina Substrate (3) @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J$ $T_{stg}$	- 55 to +150	$^\circ\text{C}$
Lead Solder Temperature — Maximum (10 Second Duration)	$T_L$	260	$^\circ\text{C}$

(1) Non-repetitive current pulse per Figure 5 and derate above  $T_A = 25^\circ\text{C}$  per Figure 6.

(2) FR-5 = 1.0 x 0.75 x 0.62 in.

(3) Alumina = 0.4 x 0.3 x 0.024 in., 99.5% alumina

Thermal Clad is a trademark of the Bergquist Company.

Preferred devices are Motorola recommended choices for future use and best overall value.

# MMBZ5V6ALT1

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

**UNIDIRECTIONAL** (Circuit tied to pins 1 and 3 or Pins 2 and 3) ( $V_F = 0.9\text{ V Max @ } I_F = 10\text{ mA}$ )

Breakdown Voltage			Max Reverse Leakage Current $I_R @ V_R$ ( $\mu\text{A}$ ) (V)	Max Zener Impedance (6)		Max Reverse Surge Current $I_{RSM(5)}$ (A)	Max Reverse Voltage @ $I_{RSM(5)}$ (Clamping Voltage) $V_{RSM}$ (V)	Maximum Temperature Coefficient of $V_Z$ ( $\text{mV}/^\circ\text{C}$ )			
$V_{ZT(4)}$ (V)				$Z_{ZT}$ @ $I_{ZT}$ ( $\Omega$ ) (mA)	$Z_{ZK}$ @ $I_{ZK}$ ( $\Omega$ ) (mA)						
Min	Nom	Max	@ $I_{ZT}$ (mA)								
5.32	5.6(7)	5.88	20	5.0	3.0	11	1600	0.25	3.0	8.0	1.26

(4)  $V_Z$  measured at pulse test current  $I_T$  at an ambient temperature of  $25^\circ\text{C}$ .

(5) Surge current waveform per Figure 5 and derate per Figure 6.

(6)  $Z_{ZT}$  and  $Z_{ZK}$  are measured by dividing the AC voltage drop across the device by the AC current supplied. The specified limits are  $I_{Z(AC)} = 0.1 I_{Z(DC)}$ , with AC frequency = 1 kHz.

(7) Other voltages may be available upon request. Please contact your Motorola representative.

## TYPICAL CHARACTERISTICS

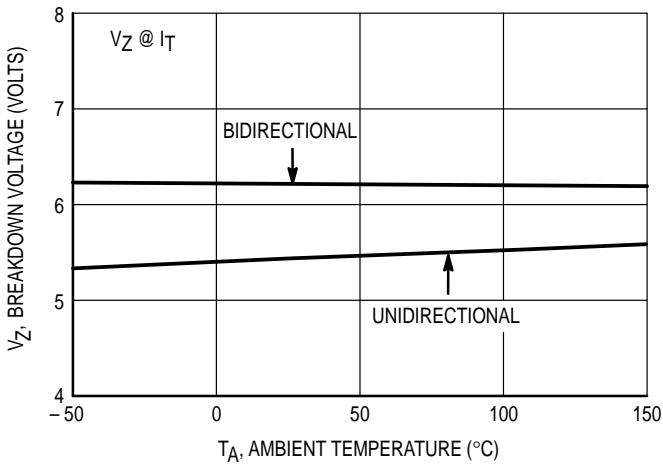


Figure 1. Typical Breakdown Voltage versus Temperature

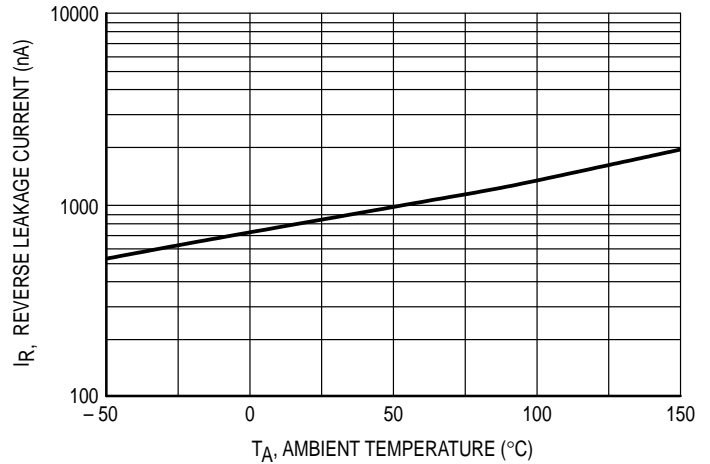


Figure 2. Typical Leakage Current versus Temperature

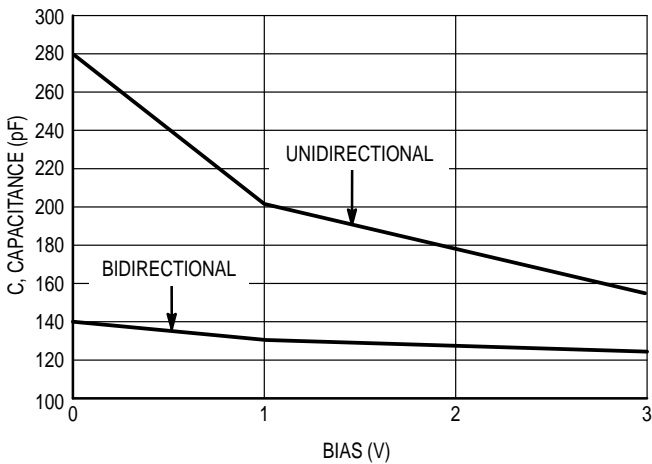


Figure 3. Typical Capacitance versus Bias Voltage

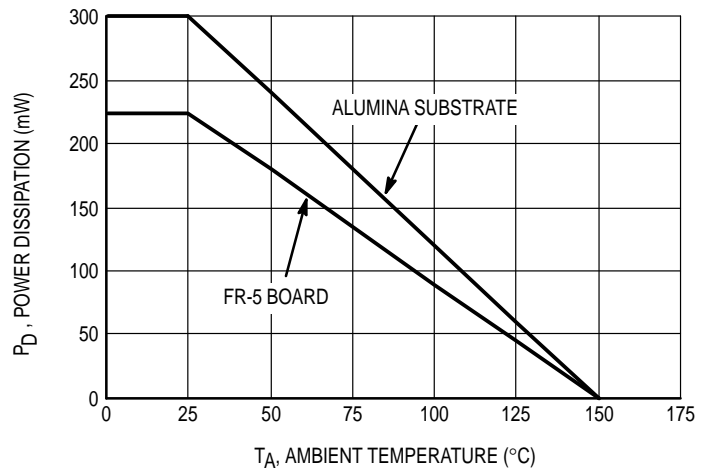


Figure 4. Steady State Power Derating Curve

# MMBZ5V6ALT1

## TYPICAL CHARACTERISTICS

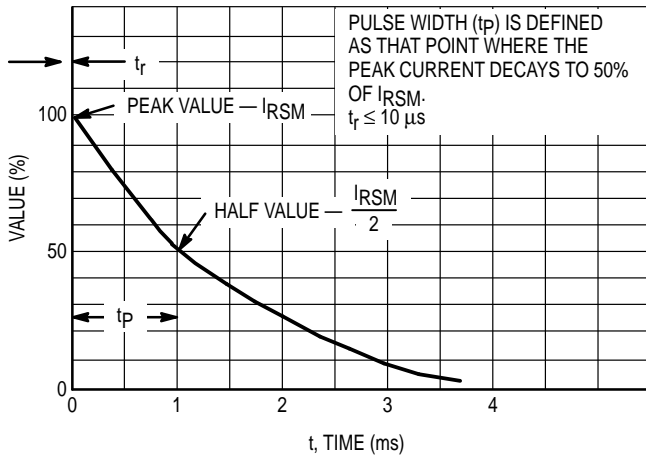


Figure 5. Pulse Waveform

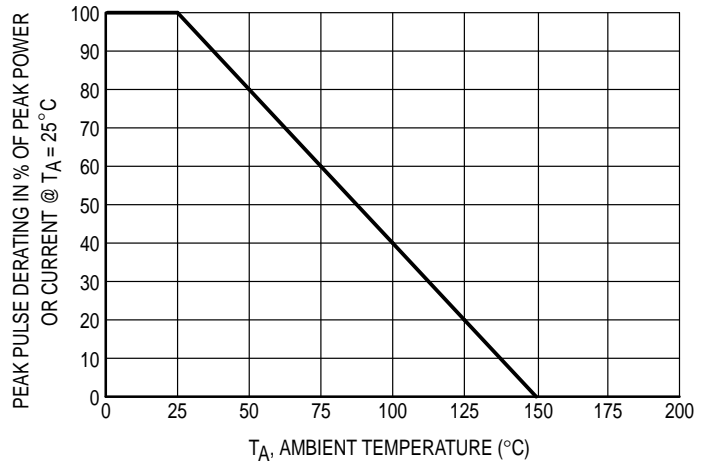


Figure 6. Pulse Derating Curve

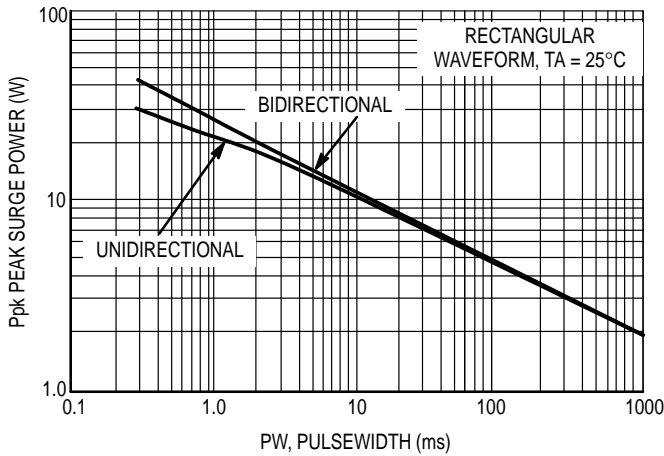


Figure 7. Maximum Non-repetitive Surge Power,  $P_{pk}$  versus PW

Power is defined as  $V_{RSM} \times I_Z(pk)$  where  $V_{RSM}$  is the clamping voltage at  $I_Z(pk)$ .

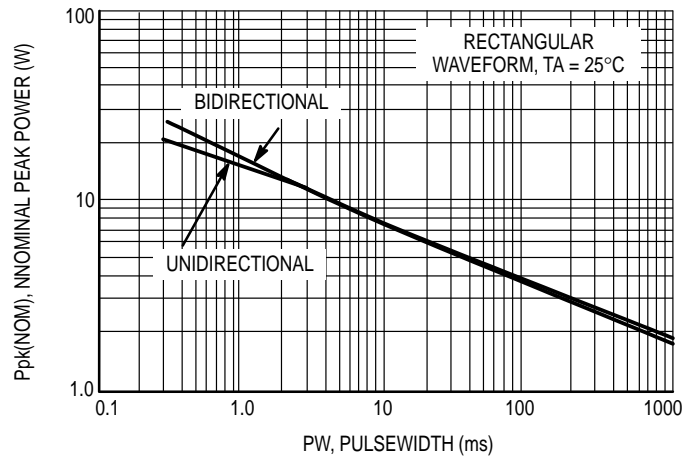


Figure 8. Maximum Non-repetitive Surge Power,  $P_{pk}(NOM)$  versus PW

Power is defined as  $V_Z(NOM) \times I_Z(pk)$  where  $V_Z(NOM)$  is the nominal zener voltage measured at the low test current used for voltage classification.

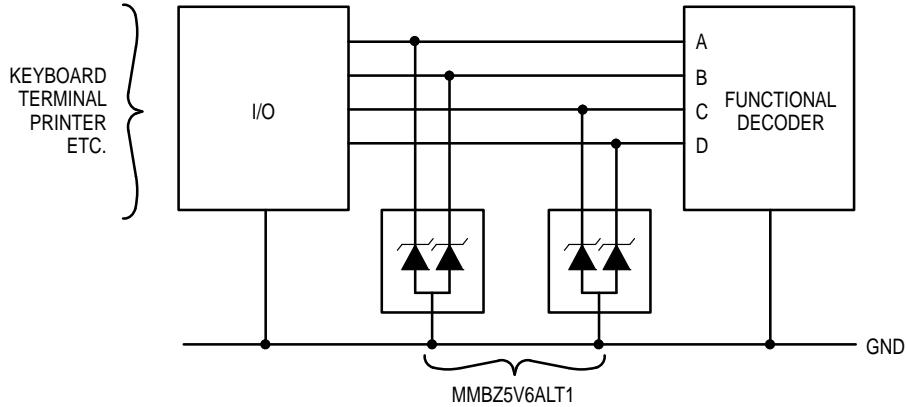
# MMBZ5V6ALT1

## TYPICAL COMMON ANODE APPLICATIONS

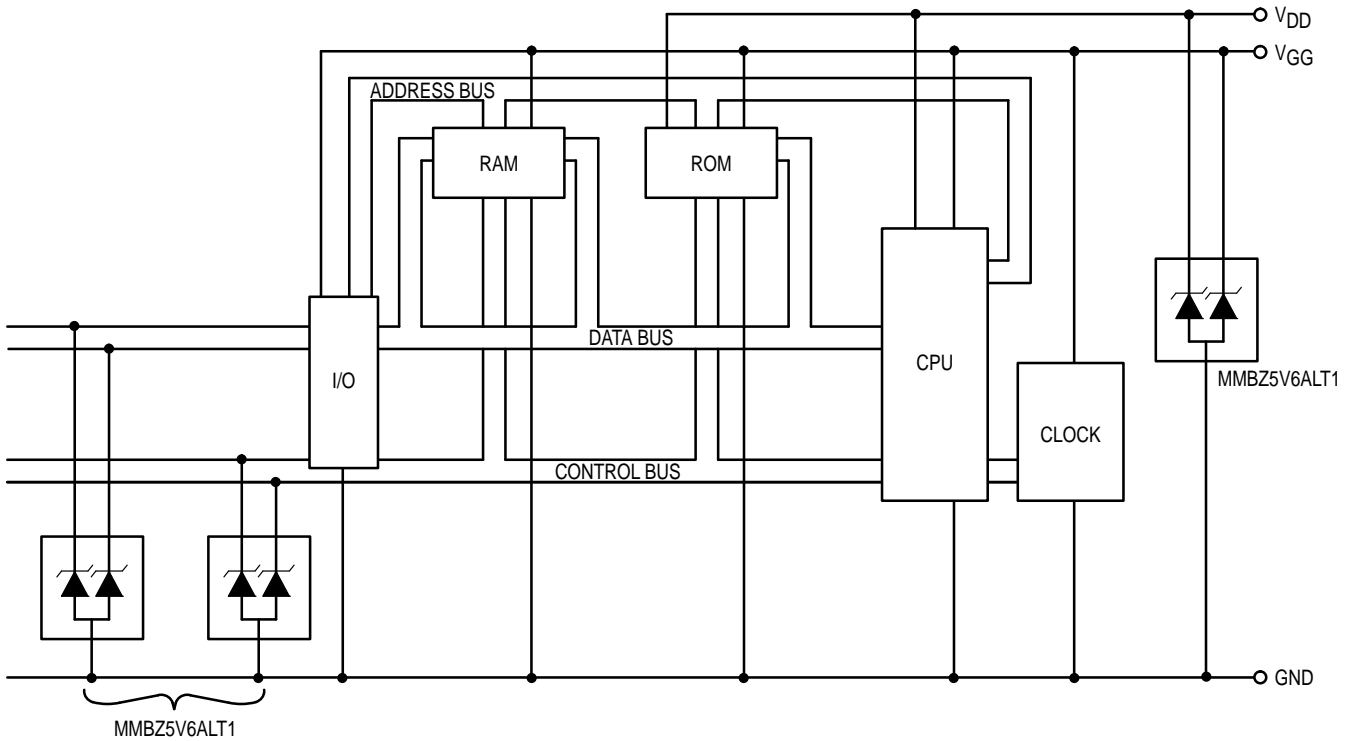
A dual junction common anode design in a SOT-23 package protects two separate lines using only one package. This adds flexibility and creativity to PCB design especially when

board space is at a premium. Two simplified examples of MMBZ5V6ALT1 TVS applications are illustrated below.

### Computer Interface Protection



### Microprocessor Protection



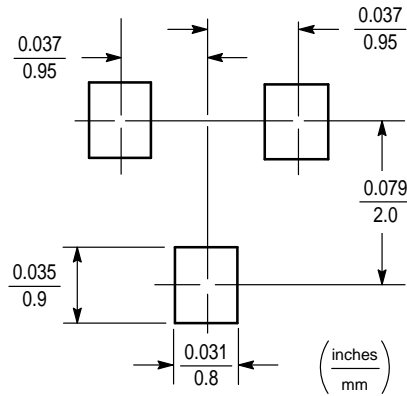
# MMBZ5V6ALT1

## INFORMATION FOR USING THE SOT-23 SURFACE MOUNT PACKAGE

### MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection interface

between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



SOT-23

### SOT-23 POWER DISSIPATION

The power dissipation of the SOT-23 is a function of the drain pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by  $T_{J(max)}$ , the maximum rated junction temperature of the die,  $R_{\theta JA}$ , the thermal resistance from the device junction to ambient, and the operating temperature,  $T_A$ . Using the values provided on the data sheet for the SOT-23 package,  $P_D$  can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature  $T_A$  of 25°C, one can calculate the power dissipation of the device which in this case is 225 milliwatts.

$$P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{556^\circ\text{C/W}} = 225 \text{ milliwatts}$$

The 556°C/W for the SOT-23 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 225 milliwatts. There are other alternatives to achieving higher power dissipation from the SOT-23 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

### SOLDERING PRECAUTIONS

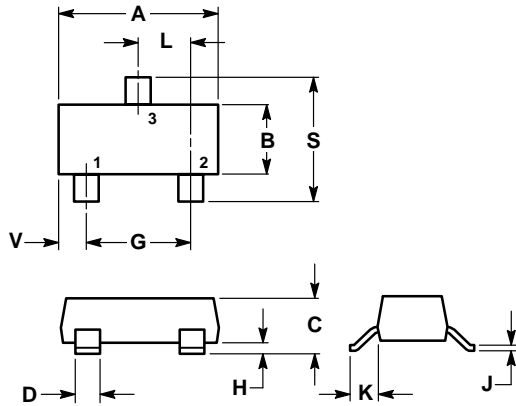
The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.\*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.
- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.

\* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

# Transient Voltage Suppressors — Surface Mounted

## 24 Watt Peak Power



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0180	0.0236	0.45	0.60
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.0984	2.10	2.50
V	0.0177	0.0236	0.45	0.60

STYLE 12:

- PIN 1. CATHODE
- CATHODE
- ANODE

CASE 318-07  
PLASTIC

(Refer to Section 10 for Surface Mount, Thermal Data and Footprint Information.)

### MULTIPLE PACKAGE QUANTITY (MPQ) REQUIREMENTS

Package Option	Type No. Suffix	MPQ (Units)
Tape and Reel	T1	3K
Tape and Reel	T3	10K

(Refer to Section 10 for more information on Packaging Specifications.)

# 15 & 27 Volt SOT-23 Dual Monolithic Common Cathode Zeners

## Transient Voltage Suppressors for ESD Protection

These dual monolithic silicon zener diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common cathode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

### Specification Features:

- SOT-23 Package Allows Either Two Separate Unidirectional Configurations or a Single Bidirectional Configuration
- Peak Power — 40 Watts @ 1.0 ms (Bidirectional), per Figure 5 Waveform
- Maximum Clamping Voltage @ Peak Pulse Current
- Low Leakage < 100 nA
- ESD Rating of Class N (exceeding 16 kV) per the Human Body Model

### Mechanical Characteristics:

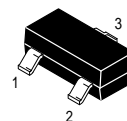
- Void Free, Transfer-Molded, Thermosetting Plastic Case
- Corrosion Resistant Finish, Easily Solderable
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- Available in 8 mm Tape and Reel

Use the Device Number to order the 7 inch/3,000 unit reel. Replace the "T1" with "T3" in the Device Number to order the 13 inch/10,000 unit reel.

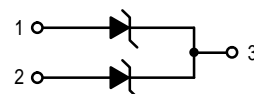
**MMBZ15VDLT1**  
**MMBZ27VCLT1**

Motorola Preferred Devices

SOT-23  
COMMON CATHODE  
DUAL ZENER  
OVERVOLTAGE  
TRANSIENT SUPPRESSORS  
40 WATTS  
PEAK POWER



CASE 318-08  
TO-236AB  
LOW PROFILE SOT-23



TERMINAL 1 - ANODE  
TERMINAL 2 - ANODE  
TERMINAL 3 - CATHODE

### THERMAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Value	Unit
Peak Power Dissipation @ 1.0 ms (1) @ T <sub>A</sub> ≤ 25°C	P <sub>pk</sub>	40	Watts
Total Power Dissipation on FR-5 Board (2) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	556	°C/W
Total Power Dissipation on Alumina Substrate (3) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	300 2.4	mW mW/°C
Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	417	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> T <sub>stg</sub>	- 55 to +150	°C
Lead Solder Temperature — Maximum (10 Second Duration)	T <sub>L</sub>	230	°C

1. Non-repetitive current pulse per Figure 5 and derate above T<sub>A</sub> = 25°C per Figure 6.
2. FR-5 = 1.0 x 0.75 x 0.62 in.
3. Alumina = 0.4 x 0.3 x 0.024 in., 99.5% alumina

Thermal Clad is a trademark of the Bergquist Company

Preferred devices are Motorola recommended choices for future use and best overall value.

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)  
**UNIDIRECTIONAL** (Circuit tied to Pins 1 and 3 or Pins 2 and 3)

( $V_F = 0.9\text{ V Max @ } I_F = 10\text{ mA}$ )

Breakdown Voltage			Reverse Voltage Working Peak $V_{RWM}$ (V)	Max Reverse Leakage Current $I_{RWM}$ $I_R$ (nA)	Max Reverse Surge Current $I_{RSM(5)}$ (A)	Max Reverse Voltage @ $I_{RSM(5)}$ (Clamping Voltage) $V_{RSM}$ (V)	Maximum Temperature Coefficient of $V_{BR}$ (mV/ $^\circ\text{C}$ )
$V_{BR(4)}$ (V)							
Min	Nom	Max	@ $I_T$ (mA)				
14.3	15	15.8	1.0	12.8	100	1.9	21.2

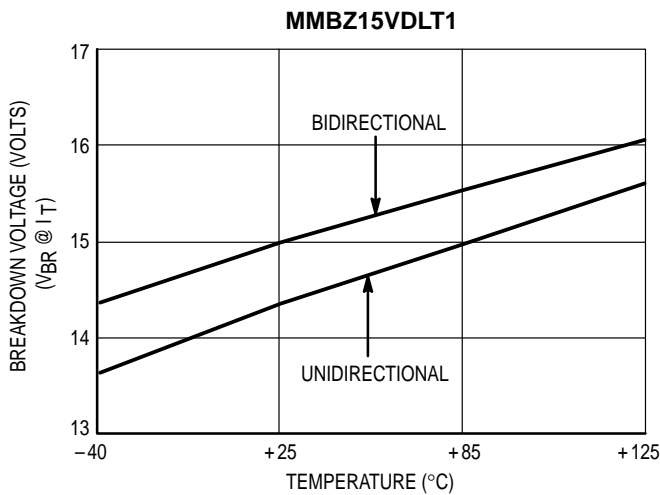
( $V_F = 1.1\text{ V Max @ } I_F = 200\text{ mA}$ )

Breakdown Voltage			Reverse Voltage Working Peak $V_{RWM}$ (V)	Max Reverse Leakage Current $I_{RWM}$ $I_R$ (nA)	Max Reverse Surge Current $I_{RSM(5)}$ (A)	Max Reverse Voltage @ $I_{RSM(5)}$ (Clamping Voltage) $V_{RSM}$ (V)	Maximum Temperature Coefficient of $V_{BR}$ (mV/ $^\circ\text{C}$ )
$V_{BR(4)}$ (V)							
Min	Nom	Max	@ $I_T$ (mA)				
25.65	27	28.35	1.0	22	50	1.0	38

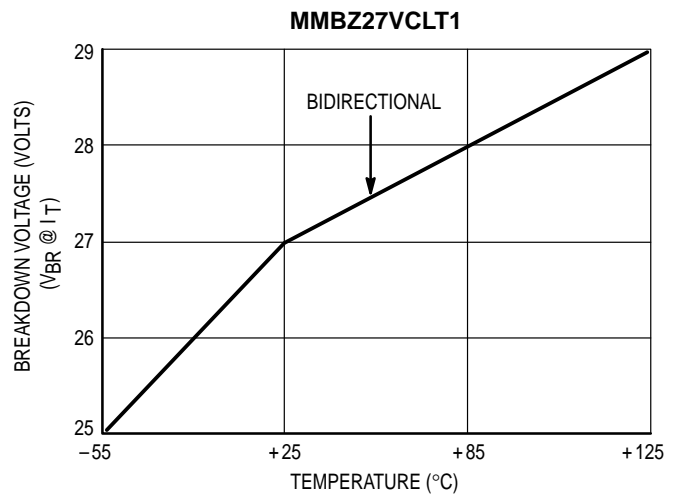
(4)  $V_{BR}$  measured at pulse test current  $I_T$  at an ambient temperature of  $25^\circ\text{C}$ .

(5) Surge current waveform per Figure 5 and derate per Figure 6.

**TYPICAL CHARACTERISTICS**



**Figure 1A. Typical Breakdown Voltage versus Temperature**



**Figure 1B. Typical Breakdown Voltage versus Temperature**



MMBZ15VDLT1

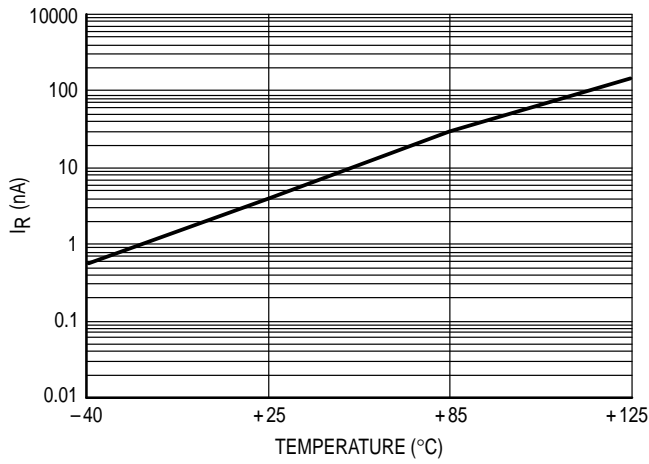


Figure 2. Typical Leakage Current versus Temperature

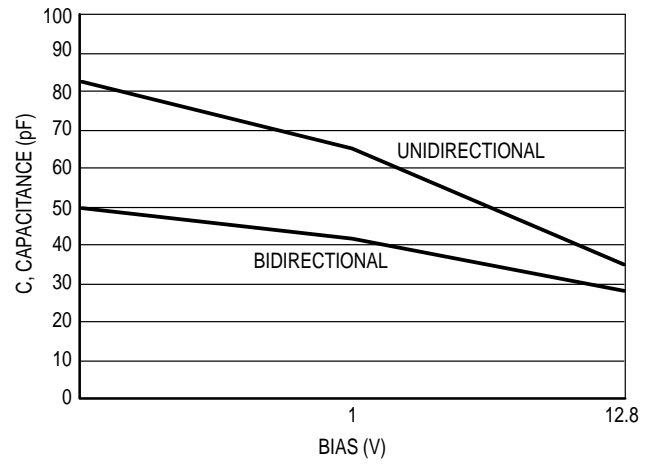


Figure 3. Typical Capacitance versus Bias Voltage

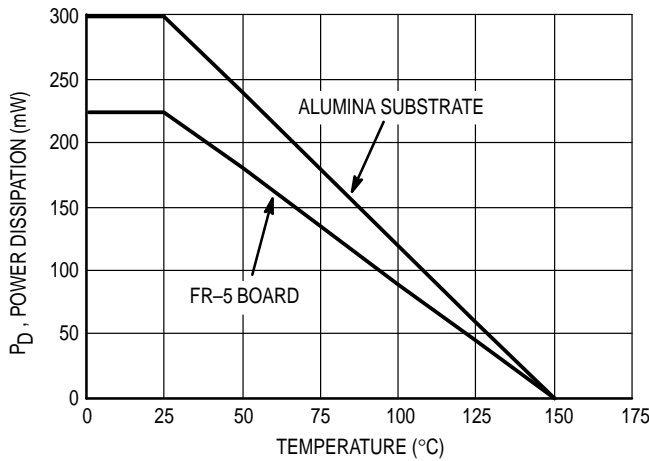


Figure 4. Steady State Power Derating Curve

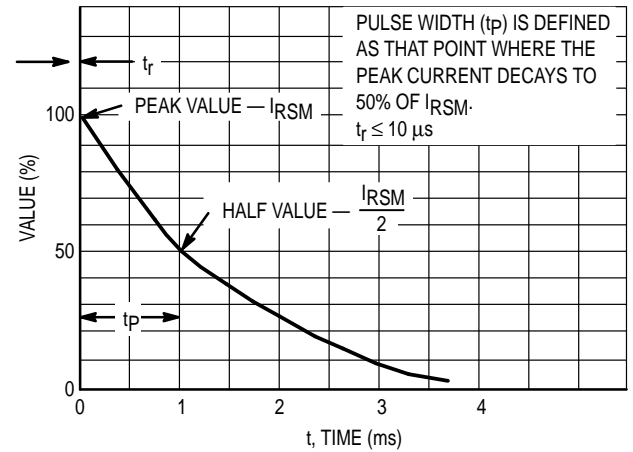


Figure 5. Pulse Waveform

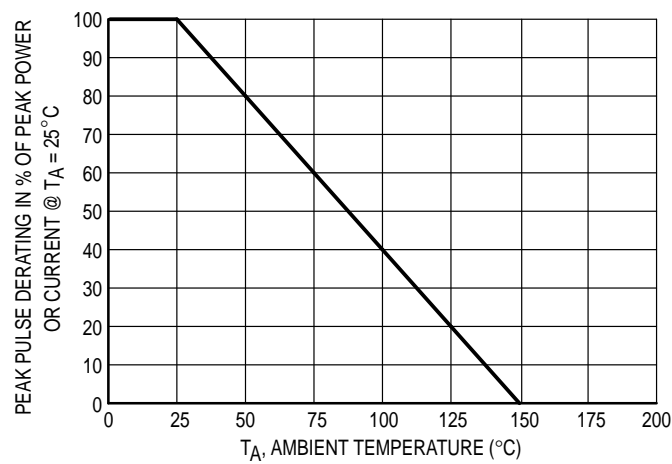


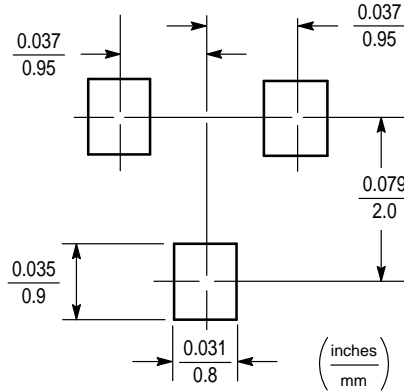
Figure 6. Pulse Derating Curve

# INFORMATION FOR USING THE SOT-23 SURFACE MOUNT PACKAGE

## MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



SOT-23

## SOT-23 POWER DISSIPATION

The power dissipation of the SOT-23 is a function of the drain pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by  $T_{J(max)}$ , the maximum rated junction temperature of the die,  $R_{\theta JA}$ , the thermal resistance from the device junction to ambient, and the operating temperature,  $T_A$ . Using the values provided on the data sheet for the SOT-23 package,  $P_D$  can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature  $T_A$  of 25°C, one can calculate the power dissipation of the device which in this case is 225 milliwatts.

$$P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{556^\circ\text{C/W}} = 225 \text{ milliwatts}$$

The 556°C/W for the SOT-23 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 225 milliwatts. There are other alternatives to achieving higher power dissipation from the SOT-23 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad™. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

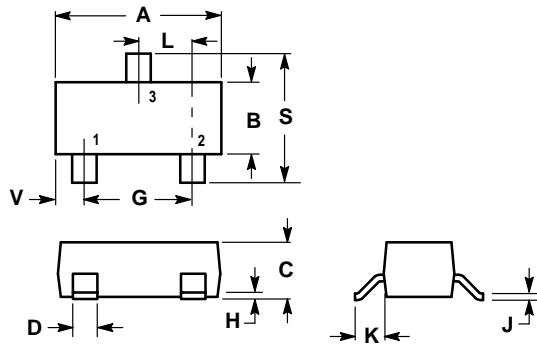
## SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.\*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.
- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.

\* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

## OUTLINE DIMENSIONS



**NOTES:**


1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

**STYLE 9:**

- PIN 1. ANODE
2. ANODE
3. CATHODE

**CASE 318-08  
ISSUE AE  
TO-236AB**

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**MOTOROLA**



**MMBZ15VDLT1/D**



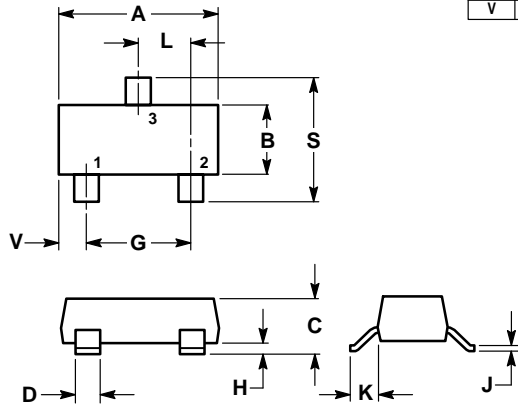
# Transient Voltage Suppressors — Surface Mounted

## 40 Watt Peak Power

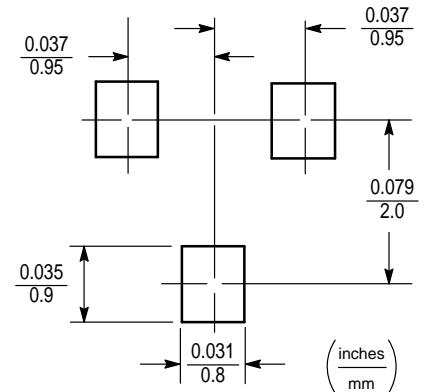
**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0180	0.0236	0.45	0.60
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.0984	2.10	2.50
V	0.0177	0.0236	0.45	0.60



STYLE 9:  
 PIN 1. ANODE  
 2. ANODE  
 3. CATHODE



**SOT-23 Footprint**

**CASE 318-07  
 PLASTIC**

(Refer to Section 10 for Surface Mount, Thermal Data and Footprint Information.)

### MULTIPLE PACKAGE QUANTITY (MPQ) REQUIREMENTS

Package Option	Type No. Suffix	MPQ (Units)
Tape and Reel	T1	3K
Tape and Reel	T3	10K

(Refer to Section 10 for more information on Packaging Specifications.)

**GENERAL DATA APPLICABLE TO ALL SERIES IN  
THIS GROUP**

**Zener Transient Voltage Suppressors**

The SMB series is designed to protect voltage sensitive components from high voltage, high energy transients. They have excellent clamping capability, high surge capability, low zener impedance and fast response time. The SMB series is supplied in Motorola's exclusive, cost-effective, highly reliable Surmetic package and is ideally suited for use in communication systems, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications.

**Specification Features:**

- Standard Zener Breakdown Voltage Range — 6.8 to 200 V
- Stand-off Voltage Range — 5 to 170 V
- Peak Power — 600 Watts @ 1 ms
- Maximum Clamp Voltage @ Peak Pulse Current
- Low Leakage < 5  $\mu$ A Above 10 V
- UL Recognition
- Response Time Typically < 1 ns

**Mechanical Characteristics:**

**CASE:** Void-free, transfer-molded, thermosetting plastic

**FINISH:** All external surfaces are corrosion resistant and leads are readily solderable

**POLARITY:** Cathode indicated by molded polarity notch. When operated in zener mode, will be positive with respect to anode

**MOUNTING POSITION:** Any

**LEADS:** Modified L-Bend providing more contact area to bond pad

**MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:** 260°C for 10 seconds

**WAFER FAB LOCATION:** Phoenix, Arizona

**ASSEMBLY/TEST LOCATION:** Seremban, Malaysia

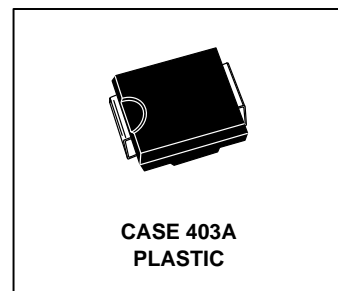
**MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Power Dissipation (1) @ $T_L \leq 25^\circ\text{C}$	$P_{PK}$	600	Watts
Forward Surge Current (2) @ $T_A = 25^\circ\text{C}$	$I_{FSM}$	100	Amps
Thermal Resistance from Junction to Lead (typical)	$R_{\theta JL}$	25	$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_J, T_{stg}$	- 65 to +150	$^\circ\text{C}$

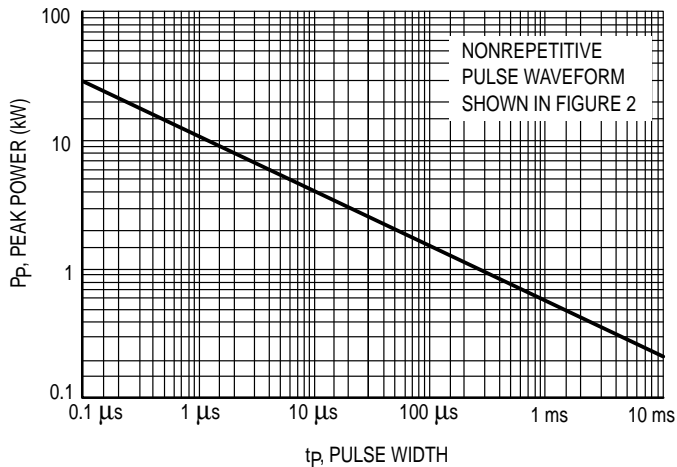
NOTES: 1. Nonrepetitive current pulse per Figure 2 and derated above  $T_A = 25^\circ\text{C}$  per Figure 3.  
2. 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute maximum.

**GENERAL  
DATA  
600 WATT  
PEAK POWER**

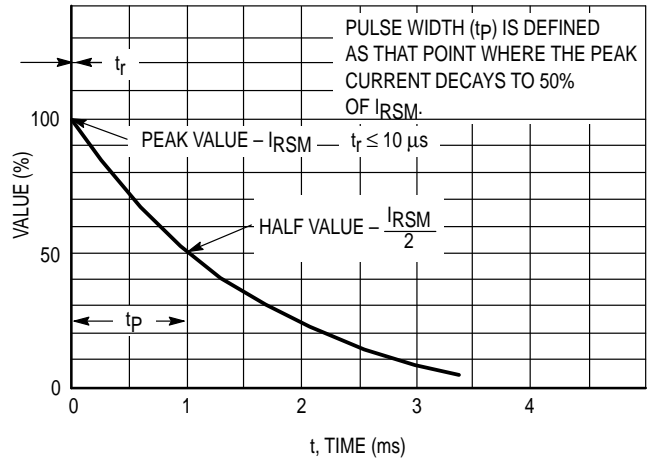
**PLASTIC SURFACE MOUNT  
ZENER OVERVOLTAGE  
TRANSIENT  
SUPPRESSORS  
6.8-200 VOLTS  
600 WATT PEAK POWER**



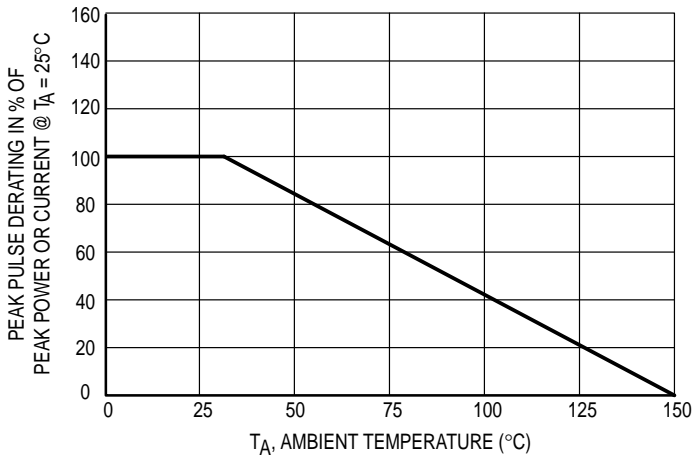
# GENERAL DATA — 600 WATT PEAK POWER



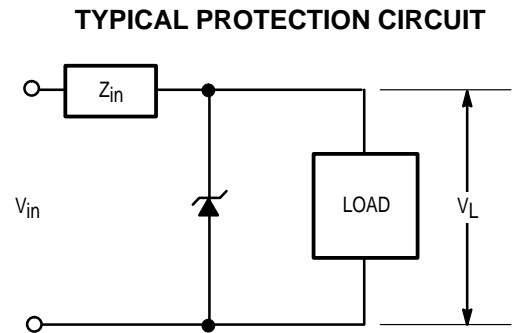
**Figure 1. Pulse Rating Curve**



**Figure 2. Pulse Waveform**



**Figure 3. Pulse Derating Curve**



## APPLICATION NOTES

### RESPONSE TIME

In most applications, the transient suppressor device is placed in parallel with the equipment or component to be protected. In this situation, there is a time delay associated with the capacitance of the device and an overshoot condition associated with the inductance of the device and the inductance of the connection method. The capacitive effect is of minor importance in the parallel protection scheme because it only produces a time delay in the transition from the operating voltage to the clamp voltage as shown in Figure 4.

The inductive effects in the device are due to actual turn-on time (time required for the device to go from zero current to full current) and lead inductance. This inductive effect produces an overshoot in the voltage across the equipment or component being protected as shown in Figure 5. Minimizing this overshoot is very important in the application, since the main purpose for adding a transient suppressor is to clamp voltage spikes. The SMB series have a very good response time, typically < 1 ns and negligible inductance. However, external inductive effects could produce unacceptable overshoot. Proper circuit layout, minimum lead lengths and placing

the suppressor device as close as possible to the equipment or components to be protected will minimize this overshoot.

Some input impedance represented by  $Z_{in}$  is essential to prevent overstress of the protection device. This impedance should be as high as possible, without restricting the circuit operation.

### DUTY CYCLE DERATING

The data of Figure 1 applies for non-repetitive conditions and at a lead temperature of 25°C. If the duty cycle increases, the peak power must be reduced as indicated by the curves of Figure 6. Average power must be derated as the lead or ambient temperature rises above 25°C. The average power derating curve normally given on data sheets may be normalized and used for this purpose.

At first glance the derating curves of Figure 6 appear to be in error as the 10 ms pulse has a higher derating factor than the 10 μs pulse. However, when the derating factor for a given pulse of Figure 6 is multiplied by the peak power value of Figure 1 for the same pulse, the results follow the expected trend.

# GENERAL DATA — 600 WATT PEAK POWER

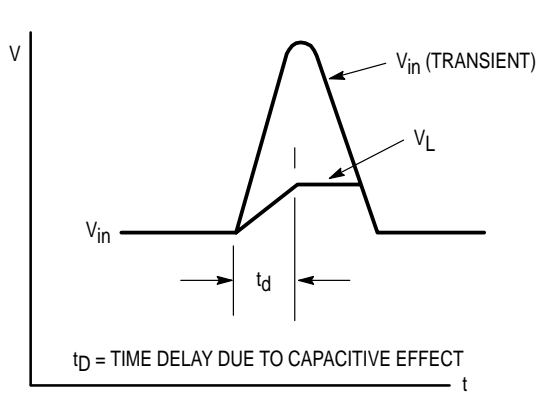


Figure 4.

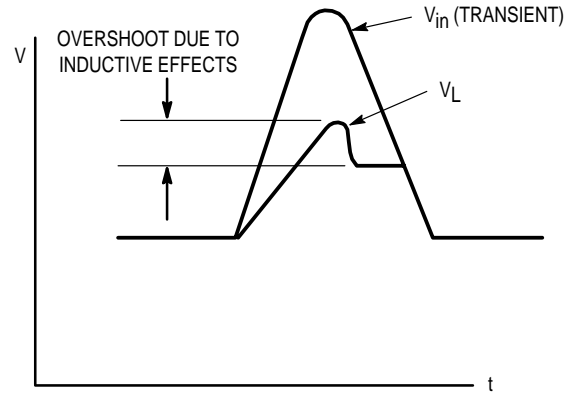


Figure 5.

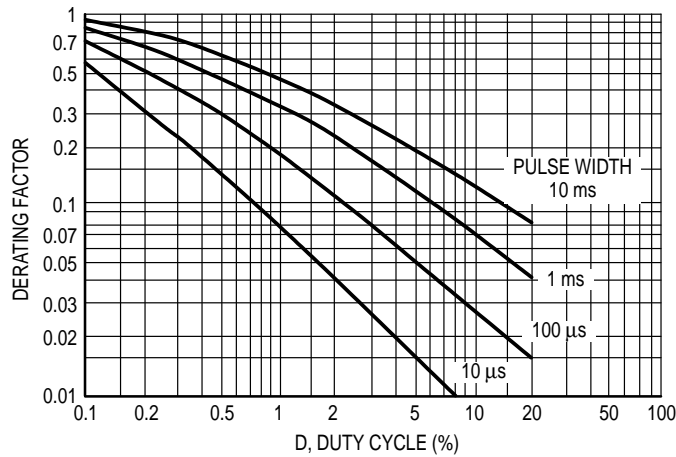


Figure 6. Typical Derating Factor for Duty Cycle

## UL RECOGNITION

The entire series has *Underwriters Laboratory Recognition* for the classification of protectors (QVGV2) under the UL standard for safety 497B and File #116110. Many competitors only have one or two devices recognized or have recognition in a non-protective category. Some competitors have no recognition at all. With the UL497B recognition, our parts successfully passed several tests including Strike Voltage

Breakdown test, Endurance Conditioning, Temperature test, Dielectric Voltage-Withstand test, Discharge test and several more.

Whereas, some competitors have only passed a flammability test for the package material, we have been recognized for much more to be included in their Protector category.



# 1SMB5.0AT3 through 1SMB170AT3

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted).

Device††	Reverse Stand-Off Voltage V <sub>R</sub> Volts (1)	Breakdown Voltage*		Maximum Clamping Voltage V <sub>C</sub> @ I <sub>pp</sub> Volts	Peak Pulse Current (See Figure 2) I <sub>pp</sub> † Amps	Maximum Reverse Leakage @ V <sub>R</sub> I <sub>R</sub> μA	Device Marking
		V <sub>BR</sub> @ I <sub>T</sub> Volts Min	mA				
<b>1SMB5.0AT3</b>	<b>5.0</b>	<b>6.40</b>	<b>10</b>	<b>9.2</b>	<b>65.2</b>	<b>800</b>	<b>KE</b>
<b>1SMB6.0AT3</b>	<b>6.0</b>	<b>6.67</b>	<b>10</b>	<b>10.3</b>	<b>58.3</b>	<b>800</b>	<b>KG</b>
1SMB6.5AT3	6.5	7.22	10	11.2	53.6	500	KK
1SMB7.0AT3	7.0	7.78	10	12.0	50.0	200	KM
1SMB7.5AT3	7.5	8.33	1.0	12.9	46.5	100	KP
1SMB8.0AT3	8.0	8.89	1.0	13.6	44.1	50	KR
1SMB8.5AT3	8.5	9.44	1.0	14.4	41.7	10	KT
1SMB9.0AT3	9.0	10.0	1.0	15.4	39.0	5.0	KV
1SMB10AT3	10	11.1	1.0	17.0	35.3	5.0	KX
1SMB11AT3	11	12.2	1.0	18.2	33.0	5.0	KZ
1SMB12AT3	12	13.3	1.0	19.9	30.2	5.0	LE
1SMB13AT3	13	14.4	1.0	21.5	27.9	5.0	LG
1SMB14AT3	14	15.6	1.0	23.2	25.8	5.0	LK
1SMB15AT3	15	16.7	1.0	24.4	24.0	5.0	LM
1SMB16AT3	16	17.8	1.0	26.0	23.1	5.0	LP
1SMB17AT3	17	18.9	1.0	27.6	21.7	5.0	LR
1SMB18AT3	18	20.0	1.0	29.2	20.5	5.0	LT
1SMB20AT3	20	22.2	1.0	32.4	18.5	5.0	LV
<b>1SMB22AT3</b>	<b>22</b>	<b>24.4</b>	<b>1.0</b>	<b>35.5</b>	<b>16.9</b>	<b>5.0</b>	<b>LX</b>
1SMB24AT3	24	26.7	1.0	38.9	15.4	5.0	LZ
1SMB26AT3	26	28.9	1.0	42.1	14.2	5.0	ME
1SMB28AT3	28	31.1	1.0	45.4	13.2	5.0	MG
1SMB30AT3	30	33.3	1.0	48.4	12.4	5.0	MK
1SMB33AT3	33	36.7	1.0	53.3	11.3	5.0	MM
1SMB36AT3	36	40.0	1.0	58.1	10.3	5.0	MP
1SMB40AT3	40	44.4	1.0	64.5	9.3	5.0	MR
1SMB43AT3	43	47.8	1.0	69.4	8.6	5.0	MT
1SMB45AT3	45	50.0	1.0	72.7	8.3	5.0	MV
1SMB48AT3	48	53.3	1.0	77.4	7.7	5.0	MX
1SMB51AT3	51	56.7	1.0	82.4	7.3	5.0	MZ
1SMB54AT3	54	60.0	1.0	87.1	6.9	5.0	NE
<b>1SMB58AT3</b>	<b>58</b>	<b>64.4</b>	<b>1.0</b>	<b>93.6</b>	<b>6.4</b>	<b>5.0</b>	<b>NG</b>
1SMB60AT3	60	66.7	1.0	96.8	6.2	5.0	NK
1SMB64AT3	64	71.1	1.0	103	5.8	5.0	NM
1SMB70AT3	70	77.8	1.0	113	5.3	5.0	NP
1SMB75AT3	75	83.3	1.0	121	4.9	5.0	NR
1SMB78AT3	78	86.7	1.0	126	4.7	5.0	NT
1SMB85AT3	85	94.4	1.0	137	4.4	5.0	NV
1SMB90AT3	90	100	1.0	146	4.1	5.0	NX
1SMB100AT3	100	111	1.0	162	3.7	5.0	NZ
1SMB110AT3	110	122	1.0	177	3.4	5.0	PE
1SMB120AT3	120	133	1.0	193	3.1	5.0	PG
1SMB130AT3	130	144	1.0	209	2.9	5.0	PK
1SMB150AT3	150	167	1.0	243	2.5	5.0	PM
1SMB160AT3	160	178	1.0	259	2.3	5.0	PP
1SMB170AT3	170	189	1.0	275	2.2	5.0	PR

Note 1: A transient suppressor is normally selected according to the reverse "Stand Off Voltage" (V<sub>R</sub>) which should be equal to or greater than the DC or continuous peak operating voltage level.

\* V<sub>BR</sub> measured at pulse test current I<sub>T</sub> at an ambient temperature of 25°C.

† Surge current waveform per Figure 2 and derate per Figure 3 of the General Data — 600 Watt at the beginning of this group.

†† T3 suffix designates tape and reel of 2500 units.

### ABBREVIATIONS AND SYMBOLS

**V<sub>R</sub>** Stand Off Voltage. Applied reverse voltage to assure a non-conductive condition (See Note 1).

**V<sub>(BR)min</sub>** This is the minimum breakdown voltage the device will exhibit and is used to assure that conduction does not occur prior to this voltage level at 25°C.

**V<sub>C</sub>** Maximum Clamping Voltage. The maximum peak voltage appearing across the transient suppressor when

subjected to the peak pulse current in a one millisecond time interval. The peak pulse voltages are the combination of voltage rise due to both the series resistance and thermal rise.

**I<sub>pp</sub>** Peak Pulse Current — See Figure 2

**P<sub>p</sub>** Peak Pulse Power

**I<sub>R</sub>** Reverse Leakage

Devices listed in bold, italic are Motorola preferred devices.

# P6SMB6.8AT3 through P6SMB200AT3

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted).

Device††	Reverse Stand-Off Voltage V <sub>R</sub> Volts (1)	Breakdown Voltage*		Maximum Clamping Voltage V <sub>C</sub> @ I <sub>pp</sub> Volts	Peak Pulse Current (See Figure 2) I <sub>pp</sub> † Amps	Maximum Reverse Leakage @ V <sub>R</sub> I <sub>R</sub> μA	Device Marking
		V <sub>BR</sub> @ I <sub>T</sub> Volts Min	mA				
1SMB10CAT3	10	11.1	1.0	17.0	35.3	5.0	KXC
1SMB11CAT3	11	12.2	1.0	18.2	33.0	5.0	KZC
1SMB12CAT3	12	13.3	1.0	19.9	30.2	5.0	LEC
1SMB13CAT3	13	14.4	1.0	21.5	27.9	5.0	LGC
1SMB14CAT3	14	15.6	1.0	23.2	25.8	5.0	LKC
<b>1SMB15CAT3</b>	<b>15</b>	<b>16.7</b>	<b>1.0</b>	<b>24.4</b>	<b>24.0</b>	<b>5.0</b>	<b>LMC</b>
1SMB16CAT3	16	17.8	1.0	26.0	23.1	5.0	LPC
1SMB17CAT3	17	18.9	1.0	27.6	21.7	5.0	LRC
1SMB18CAT3	18	20.0	1.0	29.2	20.5	5.0	LTC
1SMB20CAT3	20	22.2	1.0	32.4	18.5	5.0	LVC
1SMB22CAT3	22	24.4	1.0	35.5	16.9	5.0	LXC
1SMB24CAT3	24	26.7	1.0	38.9	15.4	5.0	LZC
1SMB26CAT3	26	28.9	1.0	42.1	14.2	5.0	MEC
1SMB28CAT3	28	31.1	1.0	45.4	13.2	5.0	MGC
1SMB30CAT3	30	33.3	1.0	48.4	12.4	5.0	MKC
1SMB33CAT3	33	36.7	1.0	53.3	11.3	5.0	MMC
1SMB36CAT3	36	40.0	1.0	58.1	10.3	5.0	MPC
1SMB40CAT3	40	44.4	1.0	64.5	9.3	5.0	MRC
1SMB43CAT3	43	47.8	1.0	69.4	8.6	5.0	MTC
1SMB45CAT3	45	50.0	1.0	72.7	8.3	5.0	MVC
1SMB48CAT3	48	53.3	1.0	77.4	7.7	5.0	MXC
1SMB51CAT3	51	56.7	1.0	82.4	7.3	5.0	MZC
1SMB54CAT3	54	60.0	1.0	87.1	6.9	5.0	NEC
1SMB58CAT3	58	64.4	1.0	93.6	6.4	5.0	NGC
1SMB60CAT3	60	66.7	1.0	96.8	6.2	5.0	NKC
1SMB64CAT3	64	71.1	1.0	103	5.8	5.0	NMC
1SMB70CAT3	70	77.8	1.0	113	5.3	5.0	NPC
1SMB75CAT3	75	83.3	1.0	121	4.9	5.0	NRC
1SMB78CAT3	78	86.7	1.0	126	4.7	5.0	NTC

Note 1: A transient suppressor is normally selected according to the reverse "Stand Off Voltage" (V<sub>R</sub>) which should be equal to or greater than the DC or continuous peak operating voltage level.

\* V<sub>BR</sub> measured at pulse test current I<sub>T</sub> at an ambient temperature of 25°C.

† Surge current waveform per Figure 2 and derate per Figure 3 of the General Data — 600 Watt at the beginning of this group.

†† T3 suffix designates tape and reel of 2500 units.

### ABBREVIATIONS AND SYMBOLS

**V<sub>R</sub>** Stand Off Voltage. Applied reverse voltage to assure a non-conductive condition (See Note 1).

**V(BR)min** This is the minimum breakdown voltage the device will exhibit and is used to assure that conduction does not occur prior to this voltage level at 25°C.

**V<sub>C</sub>** Maximum Clamping Voltage. The maximum peak voltage appearing across the transient suppressor when

**I<sub>pp</sub>**  
**P<sub>p</sub>**  
**I<sub>R</sub>**

subjected to the peak pulse current in a one millisecond time interval. The peak pulse voltages are the combination of voltage rise due to both the series resistance and thermal rise.

Peak Pulse Current — See Figure 2

Peak Pulse Power

Reverse Leakage

Devices listed in bold, italic are Motorola preferred devices.

# 1SMB10CAT3 through 1SMB78CAT3

## Bi-Directional

ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  unless otherwise noted)  $V_F = 3.5\text{ V Max}$ ,  $I_F^{**} = 50\text{ A}$  for all types.

Device††	Breakdown Voltage*				Working Peak Reverse Voltage $V_{RWM}$ Volts	Maximum Reverse Leakage @ $V_{RWM}$ $I_R$ $\mu\text{A}$	Maximum Reverse Surge Current $I_{RSM}^\dagger$ Amps	Maximum Reverse Voltage @ $I_{RSM}$ (Clamping Voltage) $V_{RSM}$ Volts	Maximum Temperature Coefficient of $V_{BR}$ %/°C	Device Marking
	$V_{BR}$ @ $I_T$ Volts									
	Min	Nom	Max	mA						
<b><i>P6SMB6.8AT3</i></b>	<b><i>6.45</i></b>	<b><i>6.8</i></b>	<b><i>7.14</i></b>	<b><i>10</i></b>	<b><i>5.8</i></b>	<b><i>1000</i></b>	<b><i>57</i></b>	<b><i>10.5</i></b>	<b><i>0.057</i></b>	<b><i>6V8A</i></b>
<b><i>P6SMB7.5AT3</i></b>	<b><i>7.13</i></b>	<b><i>7.5</i></b>	<b><i>7.88</i></b>	<b><i>10</i></b>	<b><i>6.4</i></b>	<b><i>500</i></b>	<b><i>53</i></b>	<b><i>11.3</i></b>	<b><i>0.061</i></b>	<b><i>7V5A</i></b>
P6SMB8.2AT3	7.79	8.2	8.61	10	7.02	200	50	12.1	0.065	8V2A
P6SMB9.1AT3	8.65	9.1	9.55	1	7.78	50	45	13.4	0.068	9V1A
<b><i>P6SMB10AT3</i></b>	<b><i>9.5</i></b>	<b><i>10</i></b>	<b><i>10.5</i></b>	<b><i>1</i></b>	<b><i>8.55</i></b>	<b><i>10</i></b>	<b><i>41</i></b>	<b><i>14.5</i></b>	<b><i>0.073</i></b>	<b><i>10A</i></b>
P6SMB11AT3	10.5	11	11.6	1	9.4	5	38	15.6	0.075	11A
P6SMB12AT3	11.4	12	12.6	1	10.2	5	36	16.7	0.078	12A
<b><i>P6SMB13AT3</i></b>	<b><i>12.4</i></b>	<b><i>13</i></b>	<b><i>13.7</i></b>	<b><i>1</i></b>	<b><i>11.1</i></b>	<b><i>5</i></b>	<b><i>33</i></b>	<b><i>18.2</i></b>	<b><i>0.081</i></b>	<b><i>13A</i></b>
<b><i>P6SMB15AT3</i></b>	<b><i>14.3</i></b>	<b><i>15</i></b>	<b><i>15.8</i></b>	<b><i>1</i></b>	<b><i>12.8</i></b>	<b><i>5</i></b>	<b><i>28</i></b>	<b><i>21.2</i></b>	<b><i>0.084</i></b>	<b><i>15A</i></b>
<b><i>P6SMB16AT3</i></b>	<b><i>15.2</i></b>	<b><i>16</i></b>	<b><i>16.8</i></b>	<b><i>1</i></b>	<b><i>13.6</i></b>	<b><i>5</i></b>	<b><i>27</i></b>	<b><i>22.5</i></b>	<b><i>0.086</i></b>	<b><i>16A</i></b>
<b><i>P6SMB18AT3</i></b>	<b><i>17.1</i></b>	<b><i>18</i></b>	<b><i>18.9</i></b>	<b><i>1</i></b>	<b><i>15.3</i></b>	<b><i>5</i></b>	<b><i>24</i></b>	<b><i>25.2</i></b>	<b><i>0.088</i></b>	<b><i>18A</i></b>
<b><i>P6SMB20AT3</i></b>	<b><i>19</i></b>	<b><i>20</i></b>	<b><i>21</i></b>	<b><i>1</i></b>	<b><i>17.1</i></b>	<b><i>5</i></b>	<b><i>22</i></b>	<b><i>27.7</i></b>	<b><i>0.09</i></b>	<b><i>20A</i></b>
<b><i>P6SMB22AT3</i></b>	<b><i>20.9</i></b>	<b><i>22</i></b>	<b><i>23.1</i></b>	<b><i>1</i></b>	<b><i>18.8</i></b>	<b><i>5</i></b>	<b><i>20</i></b>	<b><i>30.6</i></b>	<b><i>0.092</i></b>	<b><i>22A</i></b>
P6SMB24AT3	22.8	24	25.2	1	20.5	5	18	33.2	0.094	24A
<b><i>P6SMB27AT3</i></b>	<b><i>25.7</i></b>	<b><i>27</i></b>	<b><i>28.4</i></b>	<b><i>1</i></b>	<b><i>23.1</i></b>	<b><i>5</i></b>	<b><i>16</i></b>	<b><i>37.5</i></b>	<b><i>0.096</i></b>	<b><i>27A</i></b>
<b><i>P6SMB30AT3</i></b>	<b><i>28.5</i></b>	<b><i>30</i></b>	<b><i>31.5</i></b>	<b><i>1</i></b>	<b><i>25.6</i></b>	<b><i>5</i></b>	<b><i>14.4</i></b>	<b><i>41.4</i></b>	<b><i>0.097</i></b>	<b><i>30A</i></b>
P6SMB33AT3	31.4	33	34.7	1	28.2	5	13.2	45.7	0.098	33A
<b><i>P6SMB36AT3</i></b>	<b><i>34.2</i></b>	<b><i>36</i></b>	<b><i>37.8</i></b>	<b><i>1</i></b>	<b><i>30.8</i></b>	<b><i>5</i></b>	<b><i>12</i></b>	<b><i>49.9</i></b>	<b><i>0.099</i></b>	<b><i>36A</i></b>
<b><i>P6SMB39AT3</i></b>	<b><i>37.1</i></b>	<b><i>39</i></b>	<b><i>41</i></b>	<b><i>1</i></b>	<b><i>33.3</i></b>	<b><i>5</i></b>	<b><i>11.2</i></b>	<b><i>53.9</i></b>	<b><i>0.1</i></b>	<b><i>39A</i></b>
P6SMB43AT3	40.9	43	45.2	1	36.8	5	10.1	59.3	0.101	43A
P6SMB47AT3	44.7	47	49.4	1	40.2	5	9.3	64.8	0.101	47A
<b><i>P6SMB51AT3</i></b>	<b><i>48.5</i></b>	<b><i>51</i></b>	<b><i>53.6</i></b>	<b><i>1</i></b>	<b><i>43.6</i></b>	<b><i>5</i></b>	<b><i>8.6</i></b>	<b><i>70.1</i></b>	<b><i>0.102</i></b>	<b><i>51A</i></b>
P6SMB56AT3	53.2	56	58.8	1	47.8	5	7.8	77	0.103	56A
P6SMB62AT3	58.9	62	65.1	1	53	5	7.1	85	0.104	62A
P6SMB68AT3	64.6	68	71.4	1	58.1	5	6.5	92	0.104	68A
P6SMB75AT3	71.3	75	78.8	1	64.1	5	5.8	103	0.105	75A
P6SMB82AT3	77.9	82	86.1	1	70.1	5	5.3	113	0.105	82A
P6SMB91AT3	86.5	91	95.5	1	77.8	5	4.8	125	0.106	91A
P6SMB100AT3	95	100	105	1	85.5	5	4.4	137	0.106	100A
P6SMB110AT3	105	110	116	1	94	5	4	152	0.107	110A
P6SMB120AT3	114	120	126	1	102	5	3.6	165	0.107	120A
P6SMB130AT3	124	130	137	1	111	5	3.3	179	0.107	130A
P6SMB150AT3	143	150	158	1	128	5	2.9	207	0.108	150A
<b><i>P6SMB160AT3</i></b>	<b><i>152</i></b>	<b><i>160</i></b>	<b><i>168</i></b>	<b><i>1</i></b>	<b><i>136</i></b>	<b><i>5</i></b>	<b><i>2.7</i></b>	<b><i>219</i></b>	<b><i>0.108</i></b>	<b><i>160A</i></b>
P6SMB170AT3	162	170	179	1	145	5	2.6	234	0.108	170A
P6SMB180AT3	171	180	189	1	154	5	2.4	246	0.108	180A
P6SMB200AT3	190	200	210	1	171	5	2.2	274	0.108	200A

\*  $V_{BR}$  measured at pulse test current  $I_T$  at an ambient temperature of  $25^\circ\text{C}$ .

\*\* 1/2 sine wave (or equivalent square wave),  $PW = 8.3\text{ ms}$ , duty cycle = 4 pulses per minute maximum.

† Surge current waveform per Figure 2 and derate per Figure 3 of the General Data — 600 Watt at the beginning of this group.

†† T3 suffix designates tape and reel of 2500 units.

Devices listed in bold, italic are Motorola preferred devices.

# P6SMB11CAT3 through P6SMB91CAT3

## Bi-Directional

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)  $V_F = 3.5\text{ V Max}$ ,  $I_F^{**} = 50\text{ A}$  for all types.

Device††	Breakdown Voltage*				Working Peak Reverse Voltage $V_{RWM}$ Volts	Maximum Reverse Leakage @ $V_{RWM}$ $I_R$ $\mu\text{A}$	Maximum Reverse Surge Current $I_{RSM}^\dagger$ Amps	Maximum Reverse Voltage @ $f_{RSM}$ (Clamping Voltage) $V_{RSM}$ Volts	Maximum Temperature Coefficient of $V_{BR}$ $\%/^\circ\text{C}$	Device Marking
	$V_{BR}$ @ $I_T$ Volts									
	Min	Nom	Max	mA						
P6SMB11CAT3	10.5	11	11.6	1	9.4	5	38	15.6	0.075	11C
P6SMB12CAT3	11.4	12	12.6	1	10.2	5	36	16.7	0.078	12C
P6SMB13CAT3	12.4	13	13.7	1	11.1	5	33	18.2	0.081	13C
P6SMB15CAT3	14.3	15	15.8	1	12.8	5	28	21.2	0.084	15C
P6SMB16CAT3	15.2	16	16.8	1	13.6	5	27	22.5	0.086	16C
P6SMB18CAT3	17.1	18	18.9	1	15.3	5	24	25.2	0.088	18C
P6SMB20CAT3	19	20	21	1	17.1	5	22	27.7	0.09	20C
P6SMB22CAT3	20.9	22	23.1	1	18.8	5	20	30.6	0.092	22C
P6SMB24CAT3	22.8	24	25.2	1	20.5	5	18	33.2	0.094	24C
P6SMB27CAT3	25.7	27	28.4	1	23.1	5	16	37.5	0.096	27C
P6SMB30CAT3	28.5	30	31.5	1	25.6	5	14.4	41.4	0.097	30C
<b>P6SMB33CAT3</b>	<b>31.4</b>	<b>33</b>	<b>34.7</b>	<b>1</b>	<b>28.2</b>	<b>5</b>	<b>13.2</b>	<b>45.7</b>	<b>0.098</b>	<b>33C</b>
P6SMB36CAT3	34.2	36	37.8	1	30.8	5	12	49.9	0.099	36C
P6SMB39CAT3	37.1	39	41	1	33.3	5	11.2	53.9	0.1	39C
P6SMB43CAT3	40.9	43	45.2	1	36.8	5	10.1	59.3	0.101	43C
P6SMB47CAT3	44.7	47	49.4	1	40.2	5	9.3	64.8	0.101	47C
P6SMB51CAT3	48.5	51	53.6	1	43.6	5	8.6	70.1	0.102	51C
P6SMB56CAT3	53.2	56	58.8	1	47.8	5	7.8	77	0.103	56C
P6SMB62CAT3	58.9	62	65.1	1	53	5	7.1	85	0.104	62C
P6SMB68CAT3	64.6	68	71.4	1	58.1	5	6.5	92	0.104	68C
P6SMB75CAT3	71.3	75	78.8	1	64.1	5	5.8	103	0.105	75C
P6SMB82CAT3	77.9	82	86.1	1	70.1	5	5.3	113	0.105	82C
P6SMB91CAT3	86.5	91	95.5	1	77.8	5	4.8	125	0.106	91C

\*  $V_{BR}$  measured at pulse test current  $I_T$  at an ambient temperature of  $25^\circ\text{C}$ .

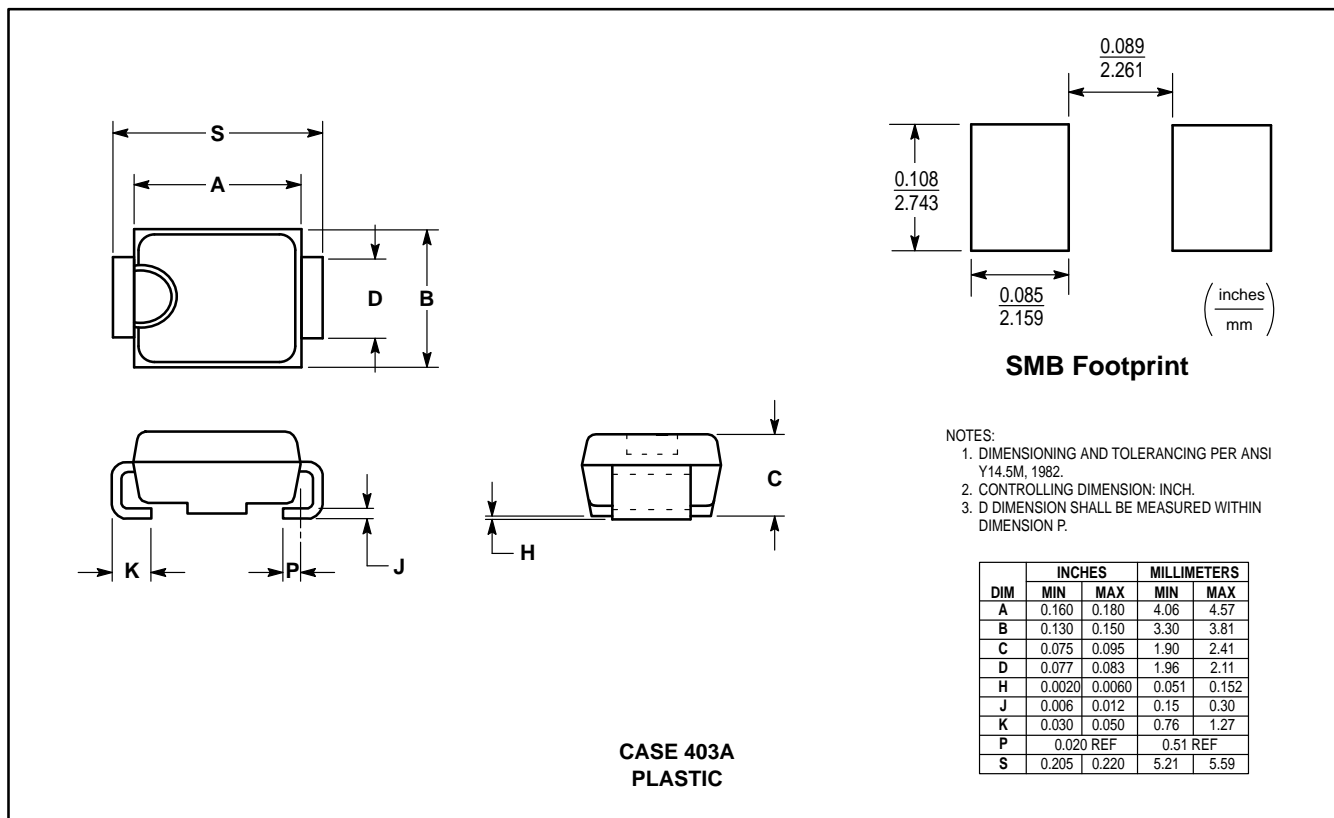
\*\* 1/2 sine wave (or equivalent square wave),  $PW = 8.3\text{ ms}$ , duty cycle = 4 pulses per minute maximum.

† Surge current waveform per Figure 2 and derate per Figure 3 of the General Data — 600 Watt at the beginning of this group.

†† T3 suffix designates tape and reel of 2500 units.

# Transient Voltage Suppressors — Surface Mounted

## 600 Watt Peak Power



(Refer to Section 10 for Surface Mount, Thermal Data and Footprint Information.)

### MULTIPLE PACKAGE QUANTITY (MPQ) REQUIREMENTS

Package Option	Type No. Suffix	MPQ (Units)
Tape and Reel	T3 (13 inch reel)	2.5K

(Refer to Section 10 for more information on Packaging Specifications.)

Devices listed in bold, italic are Motorola preferred devices.

**GENERAL DATA APPLICABLE TO ALL SERIES IN THIS GROUP**

**Zener Transient Voltage Suppressors**

The SMC series is designed to protect voltage sensitive components from high voltage, high energy transients. They have excellent clamping capability, high surge capability, low zener impedance and fast response time. The SMC series is supplied in Motorola's exclusive, cost-effective, highly reliable Surmetic package and is ideally suited for use in communication systems, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications.

**Specification Features:**

- Standard Zener Breakdown Voltage Range — 6.8 to 91 V
- Stand-off Voltage Range — 5 to 78 V
- Peak Power — 1500 Watts @ 1 ms
- Maximum Clamp Voltage @ Peak Pulse Current
- Low Leakage < 5  $\mu$ A Above 10 V
- UL Recognition
- Maximum Temperature Coefficient Specified
- Available in Tape and Reel
- Response Time Typically < 1 ns

**Mechanical Characteristics:**

**CASE:** Void-free, transfer-molded, thermosetting plastic

**FINISH:** All external surfaces are corrosion resistant and leads are readily solderable

**POLARITY:** Cathode indicated by molded polarity notch. When operated in zener mode, will be positive with respect to anode

**MOUNTING POSITION:** Any

**LEADS:** Modified L-Bend providing more contact area to bond pads

**MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:** 260°C for 10 seconds

**WAFER FAB LOCATION:** Phoenix, Arizona

**ASSEMBLY/TEST LOCATION:** Seremban, Malaysia

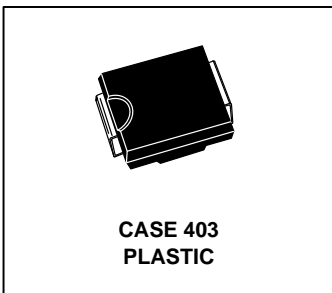
**MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Power Dissipation (1) @ $T_L \leq 25^\circ\text{C}$	PPK	1500	Watts
Forward Surge Current (2) @ $T_A = 25^\circ\text{C}$	I <sub>FSM</sub>	200	Amps
Thermal Resistance from Junction to Lead (typical)	R <sub><math>\theta</math>JL</sub>	15	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 65 to +150	$^\circ\text{C}$

NOTES: 1. Nonrepetitive current pulse per Figure 2 and derated above  $T_A = 25^\circ\text{C}$  per Figure 3.  
 2. 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute maximum.

**GENERAL  
 DATA  
 1500 WATT  
 PEAK POWER**

**PLASTIC SURFACE MOUNT  
 ZENER OVERVOLTAGE  
 TRANSIENT  
 SUPPRESSORS  
 6.8-91 VOLTS  
 1500 WATT PEAK POWER**



# GENERAL DATA — 1500 WATT PEAK POWER

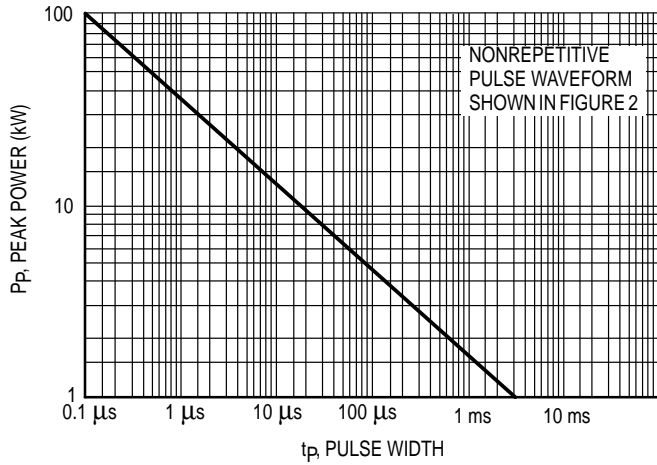


Figure 1. Pulse Rating Curve

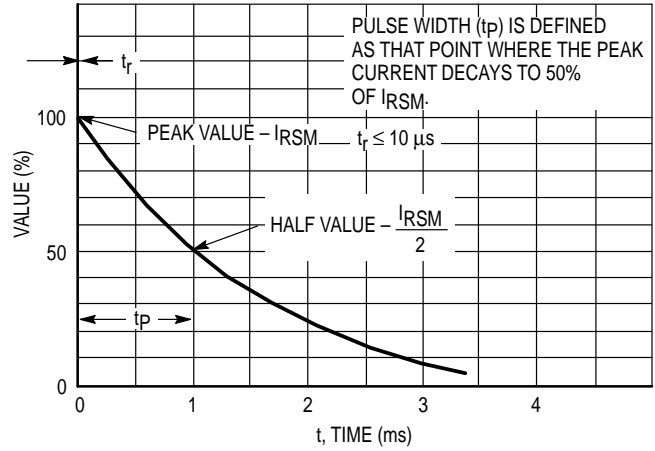


Figure 2. Pulse Waveform

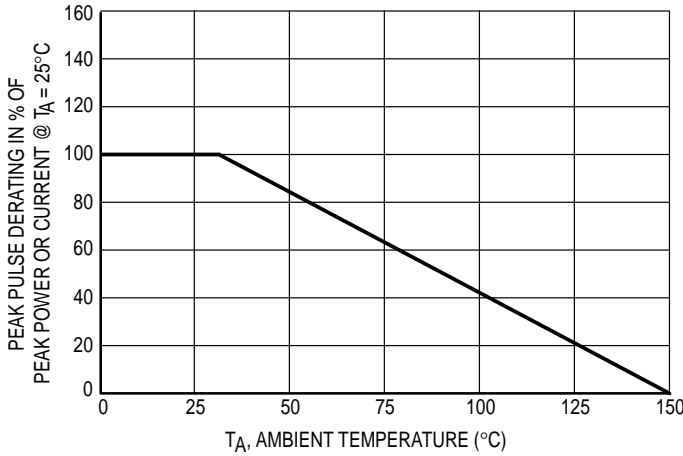


Figure 3. Pulse Derating Curve

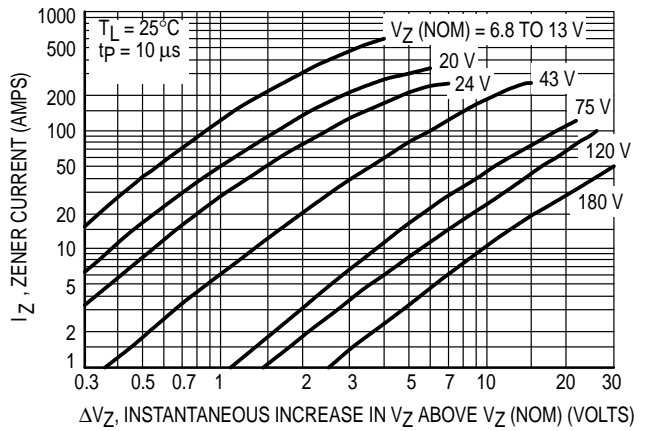


Figure 4. Dynamic Impedance

## UL RECOGNITION

The entire series has *Underwriters Laboratory Recognition* for the classification of protectors (QGV2) under the UL standard for safety 497B and File #116110. Many competitors only have one or two devices recognized or have recognition in a non-protective category. Some competitors have no recognition at all. With the UL497B recognition, our parts successfully passed several tests including Strike Voltage

Breakdown test, Endurance Conditioning, Temperature test, Dielectric Voltage-Withstand test, Discharge test and several more.

Whereas, some competitors have only passed a flammability test for the package material, we have been recognized for much more to be included in their Protector category.

# GENERAL DATA — 1500 WATT PEAK POWER

## APPLICATION NOTES

### RESPONSE TIME

In most applications, the transient suppressor device is placed in parallel with the equipment or component to be protected. In this situation, there is a time delay associated with the capacitance of the device and an overshoot condition associated with the inductance of the device and the inductance of the connection method. The capacitive effect is of minor importance in the parallel protection scheme because it only produces a time delay in the transition from the operating voltage to the clamp voltage as shown in Figure 5.

The inductive effects in the device are due to actual turn-on time (time required for the device to go from zero current to full current) and lead inductance. This inductive effect produces an overshoot in the voltage across the equipment or component being protected as shown in Figure 6. Minimizing this overshoot is very important in the application, since the main purpose for adding a transient suppressor is to clamp voltage spikes. The SMC series have a very good response time, typically  $< 1$  ns and negligible inductance. However, external inductive effects could produce unacceptable overshoot. Proper circuit layout, minimum lead lengths and placing the

suppressor device as close as possible to the equipment or components to be protected will minimize this overshoot.

Some input impedance represented by  $Z_{in}$  is essential to prevent overstress of the protection device. This impedance should be as high as possible, without restricting the circuit operation.

### DUTY CYCLE DERATING

The data of Figure 1 applies for non-repetitive conditions and at a lead temperature of  $25^{\circ}\text{C}$ . If the duty cycle increases, the peak power must be reduced as indicated by the curves of Figure 7. Average power must be derated as the lead or ambient temperature rises above  $25^{\circ}\text{C}$ . The average power derating curve normally given on data sheets may be normalized and used for this purpose.

At first glance the derating curves of Figure 7 appear to be in error as the 10 ms pulse has a higher derating factor than the 10  $\mu\text{s}$  pulse. However, when the derating factor for a given pulse of Figure 7 is multiplied by the peak power value of Figure 1 for the same pulse, the results follow the expected trend.

### TYPICAL PROTECTION CIRCUIT

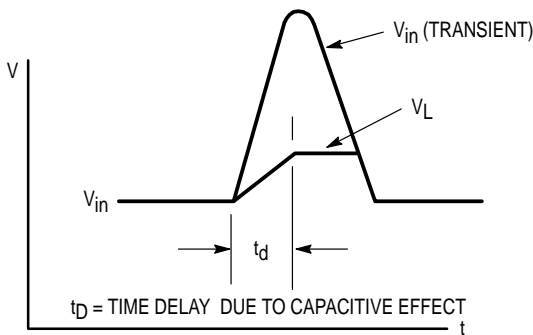
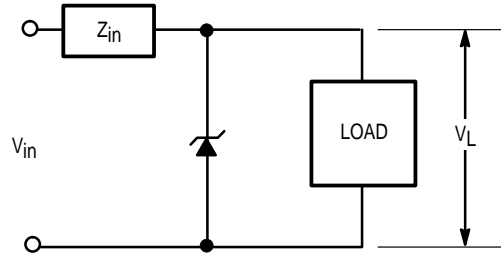


Figure 5.

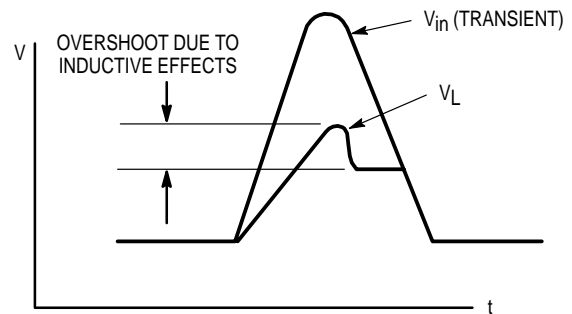


Figure 6.

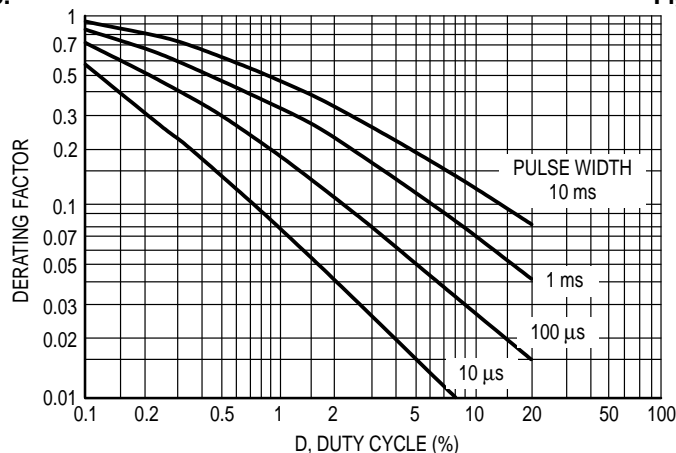


Figure 7. Typical Derating Factor for Duty Cycle



# 1SMC5.0AT3 through 1SMC78AT3

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted).

Device††	Reverse Stand-Off Voltage V <sub>R</sub> Volts (1)	Breakdown Voltage* V <sub>BR</sub> @ I <sub>T</sub>		Maximum Clamping Voltage V <sub>C</sub> @ I <sub>pp</sub> Volts	Peak Pulse Current (See Figure 2) I <sub>pp</sub> † Amps	Maximum Reverse Leakage @ V <sub>R</sub> I <sub>R</sub> μA	Device Marking
		Volts Min	mA				
1SMC5.0AT3	5.0	6.40	10	9.2	163.0	1000	GDE
1SMC6.0AT3	6.0	6.67	10	10.3	145.6	1000	GDG
1SMC6.5AT3	6.5	7.22	10	11.2	133.9	500	GDK
1SMC7.0AT3	7.0	7.78	10	12.0	125.0	200	GDM
1SMC7.5AT3	7.5	8.33	1.0	12.9	116.3	100	GDP
1SMC8.0AT3	8.0	8.89	1.0	13.6	110.3	50	GDR
1SMC8.5AT3	8.5	9.44	1.0	14.4	104.2	20	GDT
1SMC9.0AT3	9.0	10.0	1.0	15.4	97.4	10	GDV
1SMC10AT3	10	11.1	1.0	17.0	88.2	5.0	GDX
1SMC11AT3	11	12.2	1.0	18.2	82.4	5.0	GDZ
1SMC12AT3	12	13.3	1.0	19.9	75.3	5.0	GEE
1SMC13AT3	13	14.4	1.0	21.5	69.7	5.0	GEG
1SMC14AT3	14	15.6	1.0	23.2	64.7	5.0	GEK
1SMC15AT3	15	16.7	1.0	24.4	61.5	5.0	GEM
1SMC16AT3	16	17.8	1.0	26.0	57.7	5.0	GEP
1SMC17AT3	17	18.9	1.0	27.6	53.3	5.0	GER
1SMC18AT3	18	20.0	1.0	29.2	51.4	5.0	GET
1SMC20AT3	20	22.2	1.0	32.4	46.3	5.0	GEV
1SMC22AT3	22	24.4	1.0	35.5	42.2	5.0	GEX
1SMC24AT3	24	26.7	1.0	38.9	38.6	5.0	GEZ
1SMC26AT3	26	28.9	1.0	42.1	35.6	5.0	GFE
1SMC28AT3	28	31.1	1.0	45.4	33.0	5.0	GFG
1SMC30AT3	30	33.3	1.0	48.4	31.0	5.0	GFK
1SMC33AT3	33	36.7	1.0	53.3	28.1	5.0	GFM
1SMC36AT3	36	40.0	1.0	58.1	25.8	5.0	GFP
1SMC40AT3	40	44.4	1.0	64.5	23.2	5.0	GFR
1SMC43AT3	43	47.8	1.0	69.4	21.6	5.0	GFT
1SMC45AT3	45	50.0	1.0	72.7	20.6	5.0	GFV
1SMC48AT3	48	53.3	1.0	77.4	19.4	5.0	GFX
1SMC51AT3	51	56.7	1.0	82.4	18.2	5.0	GFZ
1SMC54AT3	54	60.0	1.0	87.1	17.2	5.0	GGE
<b>1SMC58AT3</b>	<b>58</b>	<b>64.4</b>	<b>1.0</b>	<b>93.6</b>	<b>16.0</b>	<b>5.0</b>	<b>GGG</b>
1SMC60AT3	60	66.7	1.0	96.8	15.5	5.0	GGK
1SMC64AT3	64	71.1	1.0	103	14.6	5.0	GGM
1SMC70AT3	70	77.8	1.0	113	13.3	5.0	GGP
1SMC75AT3	75	83.3	1.0	121	12.4	5.0	GGR
1SMC78AT3	78	86.7	1.0	126	11.4	5.0	GGT

Note 1: A transient suppressor is normally selected according to the reverse "Stand Off Voltage" (V<sub>R</sub>) which should be equal to or greater than the DC or continuous peak operating voltage level.

\* V<sub>BR</sub> measured at pulse test current I<sub>T</sub> at an ambient temperature of 25°C.

† Surge current waveform per Figure 2 and derate per Figure 3 of the General Data — 1500 Watt at the beginning of this group.

†† T3 suffix designates tape and reel of 2500 units.

### ABBREVIATIONS AND SYMBOLS

**V<sub>R</sub>** Stand Off Voltage. Applied reverse voltage to assure a non-conductive condition (See Note 1).

**V<sub>(BR)min</sub>** This is the minimum breakdown voltage the device will exhibit and is used to assure that conduction does not occur prior to this voltage level at 25°C.

**V<sub>C</sub>** Maximum Clamping Voltage. The maximum peak voltage appearing across the transient suppressor when

subjected to the peak pulse current in a one millisecond time interval. The peak pulse series resistance and thermal rise.

**I<sub>pp</sub>** Peak Pulse Current — See Figure 2

**P<sub>p</sub>** Peak Pulse Power

**I<sub>R</sub>** Reverse Leakage

Devices listed in bold, italic are Motorola preferred devices.

# 1SMC6.8AT3 through 1.5SMC91AT3

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)  $V_F = 3.5\text{ V Max}$ ,  $I_F^{**} = 100\text{ A}$  for all types.

Device††	Breakdown Voltage*				Working Peak Reverse Voltage $V_{RWM}$ Volts	Maximum Reverse Leakage @ $V_{RWM}$ $I_R$ $\mu\text{A}$	Maximum Reverse Surge Current $I_{RSM}^\dagger$ Amps	Maximum Reverse Voltage @ $I_{RSM}$ (Clamping Voltage) $V_{RSM}$ Volts	Maximum Temperature Coefficient of $V_{BR}$ $\%/^\circ\text{C}$	Device Marking
	$V_{BR}$ @ $I_T$ Volts									
	Min	Nom	Max	mA						
1.5SMC6.8AT3	6.45	6.8	7.14	10	5.8	1000	143	10.5	0.057	6V8A
1.5SMC7.5AT3	7.13	7.5	7.88	10	6.4	500	132	11.3	0.061	7V5A
1.5SMC8.2AT3	7.79	8.2	8.61	10	7.02	200	124	12.1	0.065	8V2A
1.5SMC9.1AT3	8.65	9.1	9.55	1	7.78	50	112	13.4	0.068	9V1A
1.5SMC10AT3	9.5	10	10.5	1	8.55	10	103	14.5	0.073	10A
1.5SMC11AT3	10.5	11	11.6	1	9.4	5	96	15.6	0.075	11A
1.5SMC12AT3	11.4	12	12.6	1	10.2	5	90	16.7	0.078	12A
1.5SMC13AT3	12.4	13	13.7	1	11.1	5	82	18.2	0.081	13A
<b>1.5SMC15AT3</b>	<b>14.3</b>	<b>15</b>	<b>15.8</b>	<b>1</b>	<b>12.8</b>	<b>5</b>	<b>71</b>	<b>21.2</b>	<b>0.084</b>	<b>15A</b>
1.5SMC16AT3	15.2	16	16.8	1	13.6	5	67	22.5	0.086	16A
1.5SMC18AT3	17.1	18	18.9	1	15.3	5	59.5	25.2	0.088	18A
1.5SMC20AT3	19	20	21	1	17.1	5	54	27.7	0.09	20A
1.5SMC22AT3	20.9	22	23.1	1	18.8	5	49	30.6	0.092	22A
<b>1.5SMC24AT3</b>	<b>22.8</b>	<b>24</b>	<b>25.2</b>	<b>1</b>	<b>20.5</b>	<b>5</b>	<b>45</b>	<b>33.2</b>	<b>0.094</b>	<b>24A</b>
1.5SMC27AT3	25.7	27	28.4	1	23.1	5	40	37.5	0.096	27A
1.5SMC30AT3	28.5	30	31.5	1	25.6	5	36	41.4	0.097	30A
<b>1.5SMC33AT3</b>	<b>31.4</b>	<b>33</b>	<b>34.7</b>	<b>1</b>	<b>28.2</b>	<b>5</b>	<b>33</b>	<b>45.7</b>	<b>0.098</b>	<b>33A</b>
<b>1.5SMC36AT3</b>	<b>34.2</b>	<b>36</b>	<b>37.8</b>	<b>1</b>	<b>30.8</b>	<b>5</b>	<b>30</b>	<b>49.9</b>	<b>0.099</b>	<b>36A</b>
<b>1.5SMC39AT3</b>	<b>37.1</b>	<b>39</b>	<b>41</b>	<b>1</b>	<b>33.3</b>	<b>5</b>	<b>28</b>	<b>53.9</b>	<b>0.1</b>	<b>39A</b>
<b>1.5SMC43AT3</b>	<b>40.9</b>	<b>43</b>	<b>45.2</b>	<b>1</b>	<b>36.8</b>	<b>5</b>	<b>25.3</b>	<b>59.3</b>	<b>0.101</b>	<b>43A</b>
<b>1.5SMC47AT3</b>	<b>44.7</b>	<b>47</b>	<b>49.4</b>	<b>1</b>	<b>40.2</b>	<b>5</b>	<b>23.2</b>	<b>64.8</b>	<b>0.101</b>	<b>47A</b>
1.5SMC51AT3	48.5	51	53.6	1	43.6	5	21.4	70.1	0.102	51A
1.5SMC56AT3	53.2	56	58.8	1	47.8	5	19.5	77	0.103	56A
1.5SMC62AT3	58.9	62	65.1	1	53	5	17.7	85	0.104	62A
1.5SMC68AT3	64.6	68	71.4	1	58.1	5	16.3	92	0.104	68A
<b>1.5SMC75AT3</b>	<b>71.3</b>	<b>75</b>	<b>78.8</b>	<b>1</b>	<b>64.1</b>	<b>5</b>	<b>14.6</b>	<b>103</b>	<b>0.105</b>	<b>75A</b>
1.5SMC82AT3	77.9	82	86.1	1	70.1	5	13.3	113	0.105	82A
1.5SMC91AT3	86.5	91	95.5	1	77.8	5	12	125	0.106	91A

\*  $V_{BR}$  measured at pulse test current  $I_T$  at an ambient temperature of  $25^\circ\text{C}$ .

\*\* 1/2 sine wave (or equivalent square wave),  $PW = 8.3\text{ ms}$ , duty cycle = 4 pulses per minute maximum.

† Surge current waveform per Figure 2 and derate per Figure 3 of General Data — 1500 Watt at the beginning of this group.

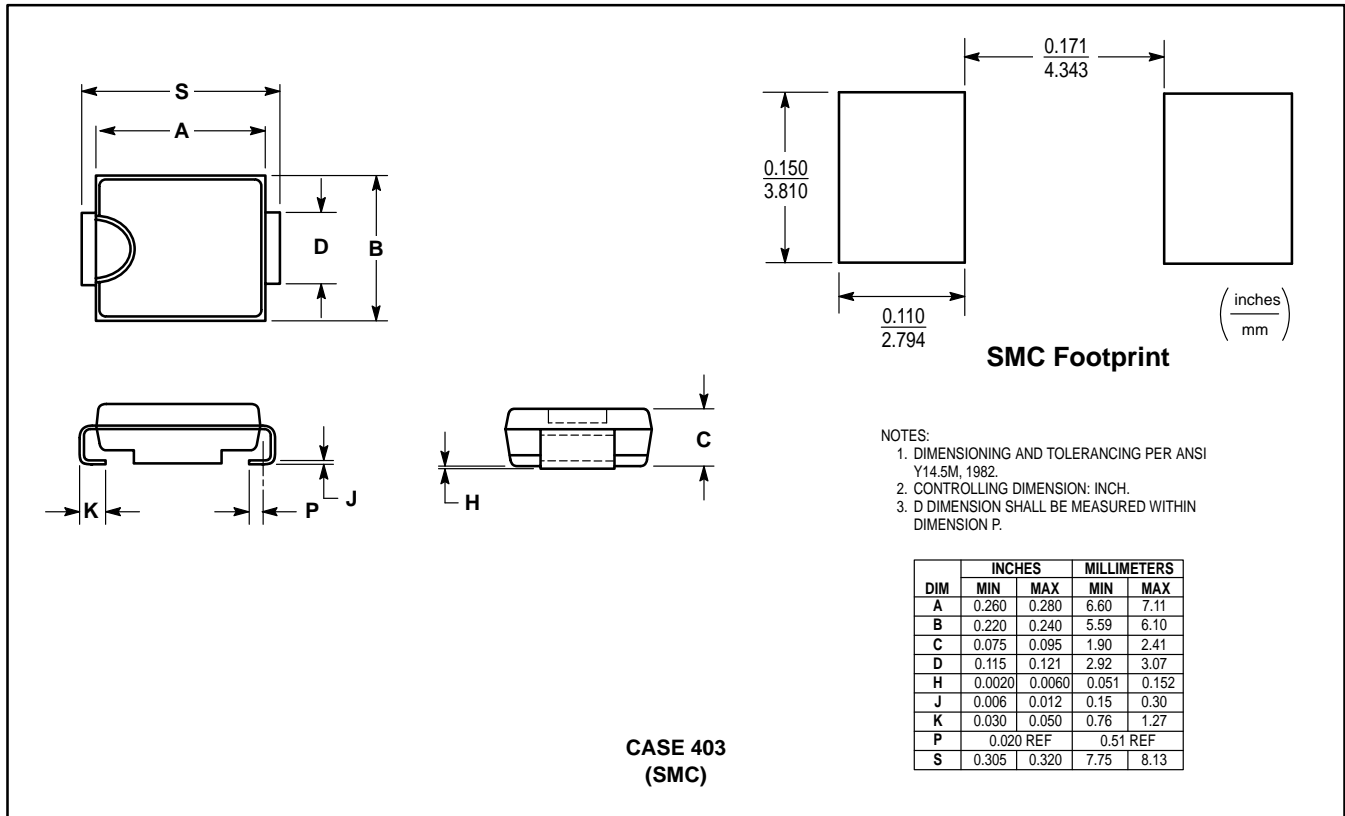
†† T3 suffix designates tape and reel of 2500 units.

Devices listed in bold, italic are Motorola preferred devices.

# 1.5SMC6.8AT3 through 1.5SMC91AT3

## Transient Voltage Suppressors — Surface Mounted

### 1500 Watt Peak Power



(Refer to Section 10 for Surface Mount, Thermal Data and Footprint Information.)

#### MULTIPLE PACKAGE QUANTITY (MPQ) REQUIREMENTS

Package Option	Type No. Suffix	MPQ (Units)
Tape and Reel	T3 (13 inch reel)	2.5K

(Refer to Section 10 for more information on Packaging Specifications.)

Devices listed in bold, italic are Motorola preferred devices.